NSN 5961-01-024-2990

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View Online at https://aerobasegroup.com/nsn/5961-01-024-2990 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.170 inches and 0.210 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Source **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 2.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 250.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Reference Number Differentiating Characteristics:** Selected item in accordance with iec dwg no. P00347250 Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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